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Total Pages : 4

CMDQ/D-23

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## ELECTRONIC DEVICES AND CIRCUITS-I

Paper-PHY-104

Time Allowed : 3 Hours]

[Maximum Marks : 60

**Note :** Attempt **five** questions in all, selecting **one** question from each Unit. Question No. **1** is compulsory. All questions carry equal marks.

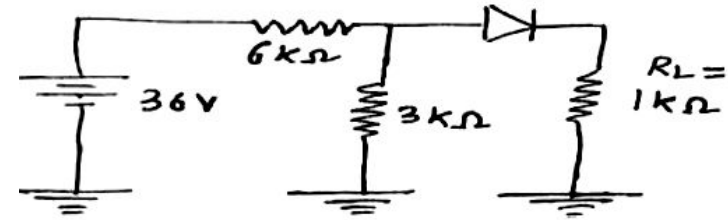
### Compulsory Question

1. (a) What are ohmic contacts? How these are made? 3
- (b) How one can control the reverse saturation current  $I_{CO}$  in a BJT amplifier? 3
- (c) What are cross-over distortions? How these can be eliminated? 3
- (d) Justify the need of composite amplifier designs. 3

### UNIT-I

2. (a) A semiconductor is doped with both donors and acceptors of concentrations  $N_D$  and  $N_A$ , respectively. Develop expressions from which to determine the electron and hole concentrations. 6

- (b) Calculate the load voltage, load current and diode power of the following circuit using Thevenin's theorem. Take the forward voltage drop across the diode 0.7V. 6

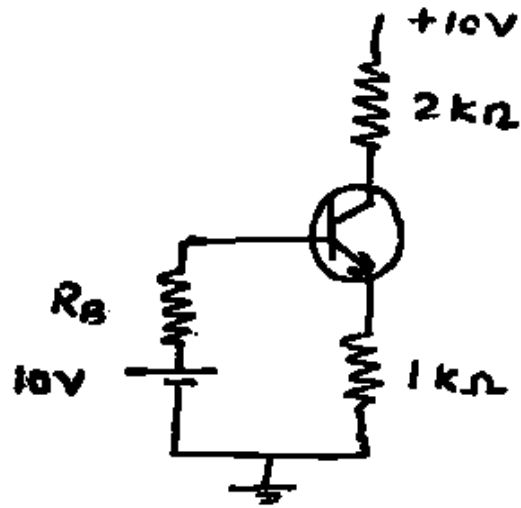


3. (a) Justify the need of clamping circuits. Further explain the operation of clamping circuit which can clamp a sinusoidal signal at  $+V_R$  volts. 6
- (b) Find the resistivity of intrinsic Si at 300K. Also find the resistivity of it if it is doped with n type impurities to the extent of 1 part in  $10^8$  Si atoms. Take Si atoms/cm<sup>3</sup> =  $5 \times 10^{22}$ ,  $\mu_n = 1300 \text{ cm}^2/\text{Vs}$  and  $\mu_p = 500 \text{ cm}^2/\text{Vs}$ . 6

### UNIT-II

4. (a) Under what operating conditions, an h-parameters model is developed for BJT amplifiers? Further develop an h-parameters model for a CC BJT amplifier. 6
- (b) What do you understand by bias compensation techniques? Explain one such technique to deal with  $I_{CO}$  variations. 6

5. (a) In the circuit shown, if  $V_{BE} = 0.6V$ ,  $\beta = 50$ , and  $I_C = 4V$ . Determine the values of  $R_B$ ,  $I_B$  and  $V_{CE}$ . 6



- (b) Discuss the effect of negative feedback on the input resistance of an amplifier. 6

### UNIT-III

6. (a) Describe CE-CC and CC-CC Darlington pair amplifiers. 6
- (b) Discuss the low and mid frequency response of a direct coupled CE amplifier. 6
7. (a) What are various noises present in an amplifier circuit? How can noise present in an amplifier be quantified? 6

- (b) Draw the circuit diagram of a two stage RC-coupled CE amplifier and explain the role of each component in the circuit. Also discuss its mid frequency response. 6

### UNIT-IV

8. (a) Describe, through suitable mathematical expressions, the performance of a Zener diode shunt voltage regulator. Also list its advantages and disadvantages. 6
- (b) Describe the operation of a class-B push-pull amplifier. Further mention its advantages and disadvantages. 6
9. (a) What are heat sinks and how we can design heat sinks for power amplifier circuits? 6
- (b) Explain the operation of shunt BJT voltage regulator and also find an expression for its input regulation factor. 6